

NCE N-Channel Enhancement Mode Power MOSFET

Description

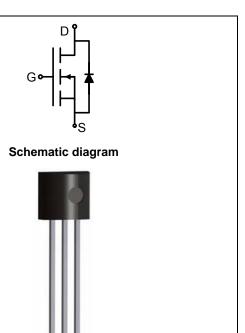
The NCE0202ZA uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- V_{DS} = 200V, I_D =2A $R_{DS(ON)}$ < 580mΩ @ V_{GS} =10V (Typ:520mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



TO-92 view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
0202ZA	NCE0202ZA	TO-92	-	-	-

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	200	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	I _D 2	
Drain Current-Pulsed (Note 1)	I _{DM}	8	Α
Maximum Power Dissipation	P _D	3	W
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	41.7	°C/W
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	200	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μΑ



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NCE0202ZA

Gate-Body Leakage Current	I_{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
On Characteristics (Note 3)	·		•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	1.2	1.8	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =2A	-	520	580	mΩ
Forward Transconductance	g FS	V _{DS} =15V,I _D =2A	-	8	-	S
Dynamic Characteristics (Note4)	·		•			
Input Capacitance	C _{lss}	\/ -25\/\/ -0\/	-	580	-	PF
Output Capacitance	C _{oss}	V_{DS} =25V, V_{GS} =0V, F=1.0MHz	-	90	-	PF
Reverse Transfer Capacitance	C _{rss}	F-1.0WHZ	-	3	-	PF
Switching Characteristics (Note 4)	·		•			
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	t _r	V_{DD} =100V, R_L =15 Ω	-	12	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =2.5 Ω	-	15	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	V =100VI =2A	-	12		nC
Gate-Source Charge	Q _{gs}	V_{DS} =100V, I_{D} =2A, V_{GS} =10V	-	2.5	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} -10V	-	3.8	-	nC
Drain-Source Diode Characteristics	·		•	•		
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =2A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	2	Α

Notes:

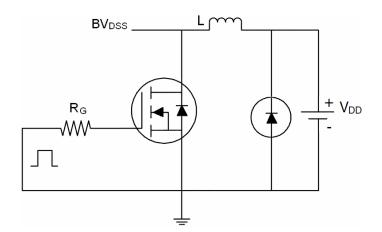
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- $\textbf{4.} \ \textbf{Guaranteed by design}, \ \textbf{not subject to production}$

Pb Free Product

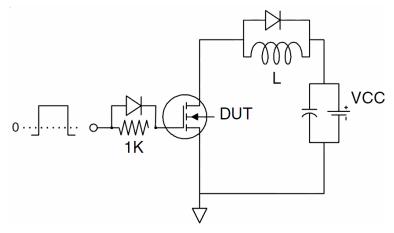


Test Circuit

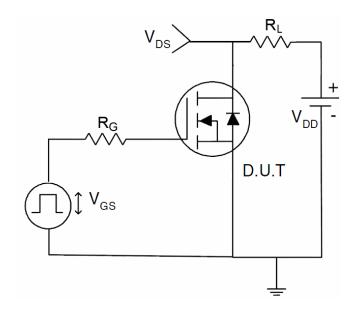
1) E_{AS} test circuit



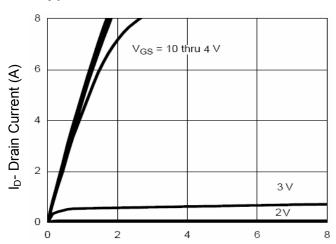
2) Gate charge test circuit



3) Switch Time Test Circuit

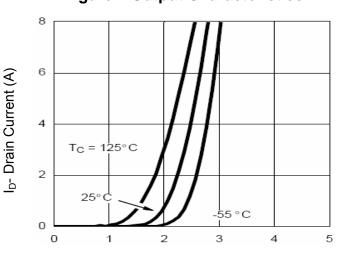


Typical Electrical and Thermal Characteristics (Curves)



Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics



Vgs Gate-Source Voltage (V)

Figure 2 Transfer Characteristics

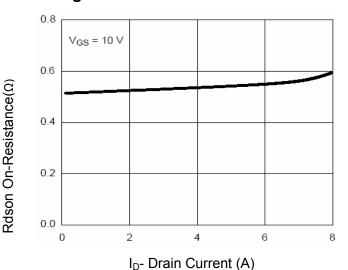
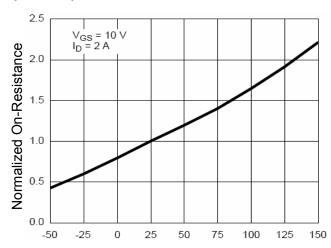
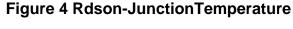
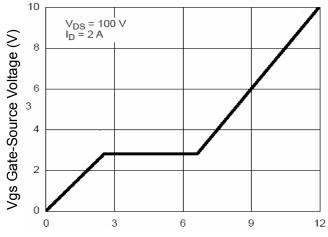


Figure 3 Rdson- Drain Current



 T_J -Junction Temperature(${}^{\circ}$ C)





Qg Gate Charge (nC)
Figure 5 Gate Charge

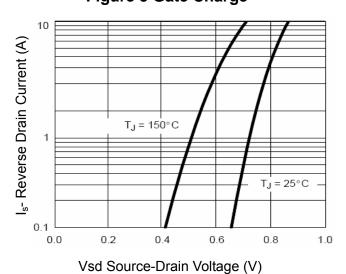
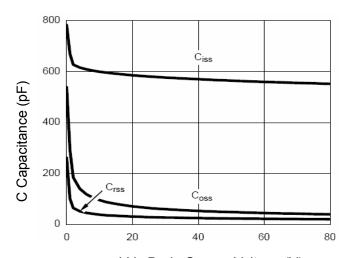
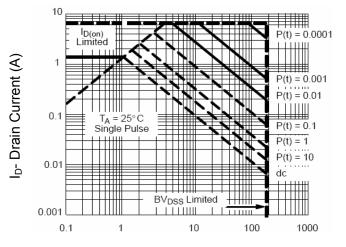


Figure 6 Source- Drain Diode Forward



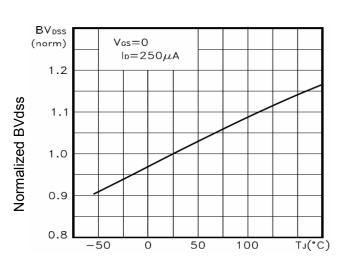
Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds



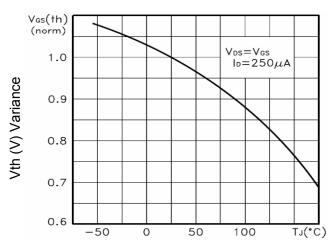
Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area



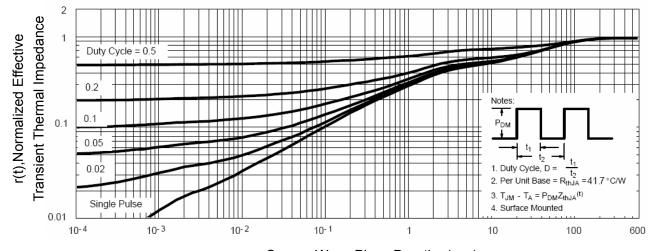
 T_J -Junction Temperature($^{\circ}$ C)

Figure 9 BV_{DSS} vs Junction Temperature



T_J-Junction Temperature(°C)

Figure 10 V_{GS(th)} vs Junction Temperature

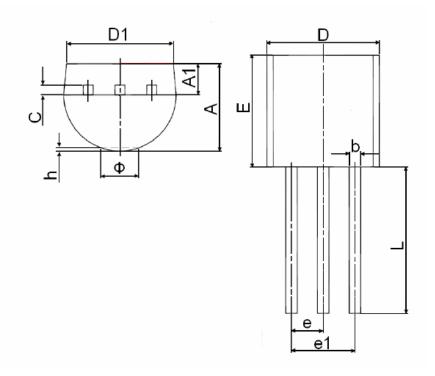


Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



TO-92 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
Α	3.300	3.700	0.130	0.146		
A1	1.100	1.400	0.043	0.055		
b	0.380	0.550	0.015	0.022		
С	0.360	0.510	0.014	0.020		
D	4.400	4.700	0.173	0.185		
D1	3.430		0.135			
Е	4.300	4.700	0.169	0.185		
е	1.270	TYP	0.050) TYP		
e1	2.440	2.640	0.096	0.104		
L	14.100	14.500	0.555	0.571		
Ф		1.600		0.063		
h	0.000	0.380	0.000	0.015		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

Pb-Free Product

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